MCS1801

mps_{_}

5V, Linear Hall-Effect Current Sensor with ±3% Accuracy Over Temperature

DESCRIPTION

V10/21

The MCS1801 is a linear Hall-effect current sensor for AC or DC current sensing. The Hall array is differential, which cancels out any stray magnetic field.

A primary conductor with a low resistance allows current to flow close to the IC, which contains high-accuracy Hall-effect sensors. This current generates a magnetic field that is sensed at two different points by the integrated Hall-effect transducers. The magnetic field difference between these two points is then converted into a voltage that is proportional to the applied current. A spinning current technique is used for a low stable offset.

The galvanic isolation between the pins of the primary conductive path and the sensor leads allows the MCS1801 to replace opto-isolators or other isolation devices.

The MCS1801 requires a minimal number of readily available, standard external components. The device's small footprint saves board area and makes it well-suited for space-constrained applications. The MCS1801 is available in an SOIC-8 package.

FEATURES

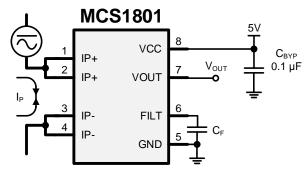
- 5V Single Supply
- Immune to External Magnetic Fields by Differential Sensing
- 200V_{RMS} Working Voltage for Basic Isolation
- -40°C to +125°C Operating Temperature
- 1.2mΩ Internal Conductor Resistance
- ±12.5A and ±25A Range
- Adjustable Bandwidth Up to 100kHz
- 4µs Output Rising Time
- Ratiometric Output from Supply Voltage
- Output Proportional to AC or DC Currents
- Factory-Trimmed for Accuracy
- No Magnetic Hysteresis
- Integrated Shield Suppressing Capacitive Coupling from Current Conductor to Die (Up to 10V/ns)
- Available in an SOIC-8 Package

APPLICATIONS

- Motor Controls
- Automotive Systems
- Load Detection and Management
- Switch-Mode Power Supplies
- Over-Current Fault Protection

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TYPICAL APPLICATION



Note:

1) V_{OUT} is proportional to I_P within the specified range. The noise vs. bandwidth tradeoff can be adjusted by connecting a capacitor (C_F) between FILT and GND.

Alcom electronics Singel 3 | B-2550 Kontich | Belgium | Tel. +32 (0)3 458 30 33 info@alcom.be | www.alcom.be Rivium 1e straat 52 | 2909 LE Capelle aan den IJssel | The Netherlands Tel. +31 (0)10 288 25 00 | info@alcom.nl | www.alcom.nl

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ORDERING INFORMATION

Part Number*	art Number* Optimized Primary Current Range(A)		Top Marking	MSL Rating
MCS1801GS-12	±12.5	160	MC180112	1
MCS1801GS-25	±25	80	MC180125	I

* For Tape & Reel, add suffix –Z (e.g. MCS1801GS-12–Z).

TOP MARKING (MCS1801GS-12)

MC180112 LLLLLLLL MPSYWW

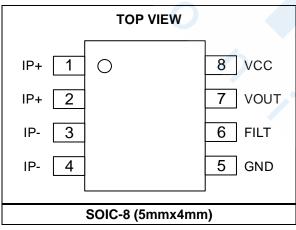
MC180112: Part number LLLLLLL: Lot number MPS: MPS prefix Y: Year code WW: Week code

TOP MARKING (MCS1801GS-25)

MC180125 LLLLLLLL MPSYWW

MC180125: Part number LLLLLLL: Lot number MPS: MPS prefix Y: Year code WW: Week code

PACKAGE REFERENCE





PIN FUNCTIONS

Pin #	Name	Description		
1, 2	IP+	Primary current (+). IP+ is a terminal for the current being sampled. These pins are internally connected together.		
3, 4 IP- Primary current (-). IP- is a terminal for the current being sampled. These pins internally connected together.				
5	GND	Ground. Signal ground terminal.		
6	 FILT FILT is a terminal for the external capacitor (C_F), which sets the bandwidth. FLT of be left floating when the bandwidth setting is not required. VOUT Analog output. 			
7				
8	VCC	Voltage supply. Connect VCC to a 5V power supply.		

ABSOLUTE MAXIMUM RATINGS 2)

Supply Voltage (V _{CC})	0.1V to +6V
Output Voltage (VOUT)	0.1V to +6V
V _{FILT}	0.1V to +6V
Junction temperature	165°C
Lead temperature	260°C
Storage temperature	-65°C to +165°C

ESD Ratings

Pin 6, Pin 7, and Pin 8 Human body model (HBM) ±2000V Pin 5, Pin 6, Pin 7, and Pin 8 Charged device model (CDM) ±2000V

Recommended Operating Conditions³⁾

Supply voltage (V_{CC}) 4.5V to 5.5V Operating junction temp (T_J)....-40°C to +125°C

Notes:

- 2) Exceeding these ratings may damage the device.
- 3) The device is not guaranteed to function outside of its operating conditions.



ISOLATION CHARACTERISTICS

Parameters	Symbol	Condition	Rating	Units
		Agency type-tested for 60 seconds in accordance with IEC62368-1. 100% Production tested at 1.2 x $V_{\rm ISO}$ for 1 second.	1000	Vrms
Maximum isolation	VIOWM	Maximum approved isolation working voltage for basic isolation, according to IEC62368-1.		Vрк
working voltage				$V_{\text{RMS}} \text{ or } V_{\text{DC}}$
External clearance	CLR	Shortest distance through the air from the IP leads to the signal leads.	4.2	mm
External creepage	ernal creepage CPG Shortest distance along the package body from the IP leads to the signal leads.		4.2	mm



MCS1801 COMMON ELECTRICAL CHARACTERISTICS 4)

Typical values are $V_{CC} = 5V$, $C_F = 0nF$, $C_L = 1nF$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted.

Parameters	Symbol	Condition	Min	Тур	Max	Units
Supply voltage	Vcc		4.5		5.5	V
VCC under-voltage lockout threshold	VCC _{UVLO}	V _{CC} rising	2	2.5	3	V
VCC under-voltage lockout hysteresis	VCCUVLO_HYS			400	750	mV
Operating supply current	lcc	Vcc = 5V		8.5	10.5	mA
Output capacitance load ⁽¹⁰⁾	CL	From V _{OUT} to GND			10	nF
Output resistive load (10)	R∟	From Vout to GND	4.7			kΩ
Primary conductor resistance ⁽¹²⁾	RP	Effective		1.2		mΩ
Frequency bandwidth (10)	f _{BW}	FILT disconnected		100		kHz
Internal filter resistance (9)	R _{Fi}			1.5		kΩ
Internal filter capacitance (9)	CFi			1		nF
Power-on time (10)	tPO	IP = IPMAX, FILT disconnected		90		μs
Rise time ⁽¹⁰⁾	tR	IP = IPMAX, FILT disconnected		4		μs
Propagation delay (10)	t _{PD}	I _P = I _{PMAX} , FILT disconnected		1.5		μs
Response time (10)	tresponse	IP = IPMAX, FILT disconnected		5		μs
Noise density ⁽¹⁰⁾	Ind	Input referred noise density		200		µA _(RMS) / √Hz
Noise (10)	IN	Input referred, 1nF on FILT (60kHz bandwidth)		50		mA _(RMS)
Nonlinearity (10)	ELIN	Across the full IP range		0.5		%
Detiemetry	KSENS	V _{CC} = 4.5 to 5.5V	97.5	100	102.5	%
Ratiometry	Kvo	$V_{CC} = 4.5$ to 5.5V, $I_P = 0A$	99	100	101	%
Zero current output voltage	$V_{OUT(Q)}$ $(I_P = 0)$	IP = 0A		Vcc / 2		V
First Hall magnetic coupling factor ⁽⁹⁾	P _{MCF1}		1.1	1.2	1.3	mT/A
Second Hall magnetic coupling factor ⁽⁹⁾	P _{MCF2}		0.60	0.65	0.70	mT/A
Hall plate matching (10)	Мн			±1		%
Saturation voltage (5)	Vout(h)	$R_L = 4.7 k\Omega$, $T_J = 25^{\circ}C$	V _{cc} - 0.5			v
- -	Vout(L)	R _L = 4.7kΩ, T _J = 25°C			0.5	V



MCS1801-12 PERFORMANCE CHARACTERISTICS (4)

$V_{CC} = 5V$, $C_F = 0nF$, $C_L = 1nF$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted.

Parameters	Symbol	Symbol Condition		Typ ⁽¹¹⁾	Max	Units
Optimized accuracy range (6)	lΡ		-12.5		+12.5	Α
Sensitivity	SENS	-12.5A≤ I _P ≤ +12.5A, T _J = 25°C		160		mV/A
Constitutty orror	F	I _P = 12.5A, T _J = 25°C to 125°C	-2.5		+2.5	%
Sensitivity error	Esens	$I_P = 12.5A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±2		%
Offerst up to $re (7)$	N	$I_P = 0A, T_J = 25^{\circ}C \text{ to } 125^{\circ}C$	-15		+15	mV
Offset voltage (7)	Voe	$I_P = 0A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±10		mV
Total output error ⁽⁸⁾	F	$I_P = 12.5A, T_J = 25^{\circ}C \text{ to } 125^{\circ}C$	-3		+3	%
Total output error (*)	Етот	$I_P = 12.5A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±2.5		%
Sensitivity error lifetime drift (10)	Esens(d)			±1		%
Total output error lifetime drift ⁽¹⁰⁾	Etot(d)			±1		%

MCS1801-25 PERFORMANCE CHARACTERISTICS (4)

$V_{CC} = 5V$, $C_F = 0nF$, $C_L = 1nF$, $T_J = -40^{\circ}C$ to $+125^{\circ}C$, unless otherwise noted.

Parameters	Symbol	Condition	Min	Typ ⁽¹¹⁾	Max	Units
Optimized accuracy range (6)	IР		-25		+25	Α
Sensitivity	SENS	$-25A \le I_P \le +25A, T_J = 25^{\circ}C$		80		mV/A
Sonoitivity orror	Earry	$I_P = 25A, T_J = 25^{\circ}C \text{ to } 125^{\circ}C$	-2.5		+2.5	%
Sensitivity error	Esens	$I_P = 25A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±2		%
Offentiveltane ⁽⁷⁾	Voe	$I_P = 0A, T_J = 25^{\circ}C \text{ to } 125^{\circ}C$	-15		+15	mV
Offset voltage (7)		$I_P = 0A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±10		mV
Total output error ⁽⁸⁾	Етот	$I_P = 25A, T_J = 25^{\circ}C \text{ to } 125^{\circ}C$	-3		+3	%
		$I_P = 25A, T_J = -40^{\circ}C \text{ to } +25^{\circ}C$		±2.5		%
Sensitivity error lifetime drift (10)	Esens(d)			±1		%
Total output error lifetime drift (10)	Etot(d)			±1		%

Notes:

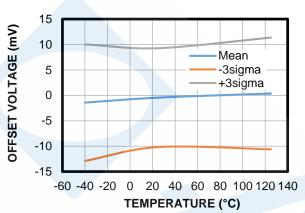
4) See the Operation section on page 10 for more details.

- 5) Beyond the maximum specified current range (I_P), the current sensor continues to provide an analog output voltage proportional to the primary current until the device reaches the high or low saturation voltage. However, nonlinearity increases when the device operates beyond the specified range (I_P).
- 6) The device can operate at higher primary current levels (I_P) and ambient temperatures (T_A), as long as the device does not exceed the maximum junction temperature (T_J (MAX)).
- 7) The offset voltage does not incorporate any error due to external magnetic fields.
- 8) Percentage of I_P , when $I_P = I_{P_MAX}$. The output filtered.
- 9) Guaranteed by design.
- 10) Guaranteed by characterization.
- 11) Typical values denoted with the "±" sign signify ±3 sigma values.
- 12) The resistance is defined as the total resistance measured from a point of the lead next to the solder joint, assuming that the two IP+ pins (and IP- pins) have the same potential (see Figure 1). This definition corresponds to the effective resistance used to estimate the Joule heating, calculated with R x I_P².

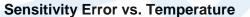
Figure 1: Total Resistance

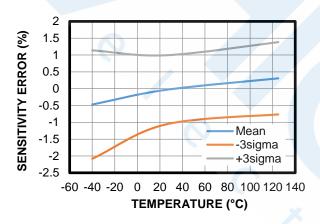
TYPICAL CHARACTERISTICS

MCS1801GS-12, unless otherwise noted.

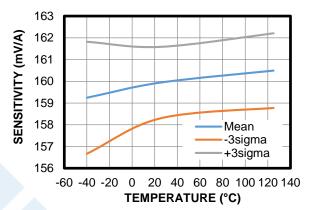


Offset Voltage vs. Temperature

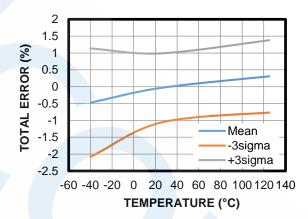




Sensitivity vs. Temperature



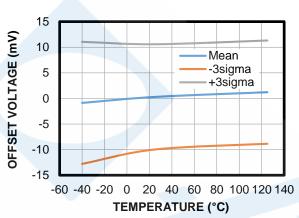
Total Error vs. Temperature





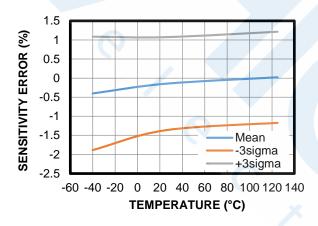
TYPICAL CHARACTERISTICS

MCS1801GS-25, unless otherwise noted.



Offset Voltage vs. Temperature

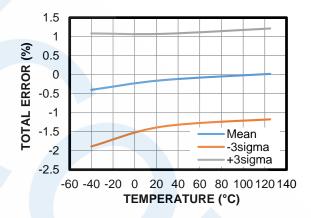




81.5 81 80.5 80 79.5 79 78.5 78 -60 -40 -20 0 20 40 60 80 100 120 140 TEMPERATURE (°C)

Sensitivity vs. Temperature







FUNCTIONAL BLOCK DIAGRAM

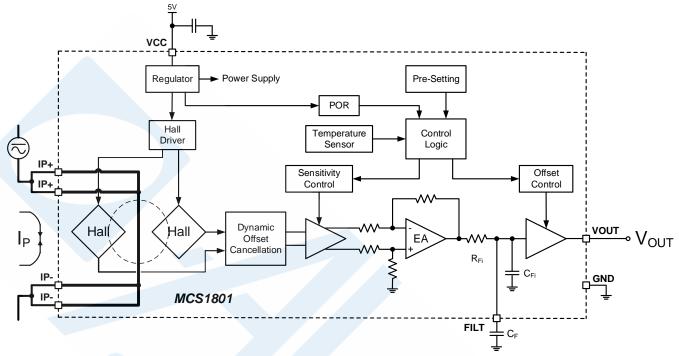


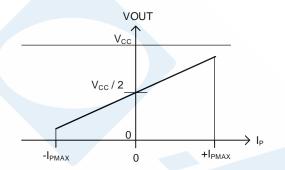
Figure 2: Functional Block Diagram



OPERATION

Current Rating

 I_{PMAX} is the rated current. The sensor output is linear, as a function of the primary current (I_P). I_{PMAX} follows the specified performances when I_P is between - I_{PMAX} and + I_{PMAX} (see Figure 3).





Sensitivity (SENS)

The sensitivity (SENS) (in mV/A) indicates how the output changes when the primary current changes. SENS the product of the average between the two coupling constants (P_{MCF1} and P_{MCF2}) (in mT/A) and the transducer gain (in mV/mT). The gain is factory-trimmed to the sensor target sensitivity.

Coupling Constants (PMCF1 and PMCF2)

Figure 4 shows a cross-section of the sensor. The first and second Hall magnetic coupling factors are defined as the amount of the vertical magnetic field (B_1 and B_2) produced at the sensing points 1 and 2, per unit of current injected in the primary conductor. Due to the asymmetrical shape of the primary conductor, the magnetic field generated at the two sensing points are different.

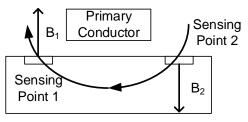


Figure 4: Cross Section of the Sensor

Noise (V_{NOISE})

The noise (V_{NOISE}) is a random deviation that cannot be removed by calibrating the device. The input's referred noise is the root mean square of the sensor's output noise (in mV), divided by the sensitivity (in mV/A). V_{NOISE} represents the smallest current that the device is able to resolve without any external signal treatment (the resolution is typically 3 times the RMS noise).

Other deviations are systematic, which means that they represent the average deviation across a large number of data points. These deviations can be removed by calibrating the device.

Zero Current Output Voltage (VOUT(Q))

 $V_{OUT(Q)}$ is the voltage output when the primary current is 0A. The nominal value is V_{CC} / 2. The variation in $V_{OUT(Q)}$ from the nominal value is due to thermal drift, as well as the factory's resolution limits related to voltage offset trimming.

Offset Voltage (VOE)

The offset voltage (V_{OE}) is the difference between V_{CC} / 2 and the zero current output voltage. To convert this voltage into amperes, divide V_{OE} by the sensitivity.

Nonlinearity (ELIN)

The primary current and sensor output should have a linear relationship, indicated by a straight line. A line that is not straight indicates nonlinearity, which is a deviation.

Nonlinearity (in %) can be calculated with Equation (1):

$$\mathsf{E}_{\text{LIN}} = \frac{\max(\mathsf{V}_{\text{OUT}}(\mathsf{I}_{\text{P}}) - \mathsf{V}_{\text{LIN}}(\mathsf{I}_{\text{P}}))}{\mathsf{V}_{\text{OUT}}(\mathsf{I}_{\text{PMAX}}) - \mathsf{V}_{\text{OUT}}(-\mathsf{I}_{\text{PMAX}})} \times 100$$
(1)

Where $V_{\text{LIN}}(I_P)$ is the approximate straight line calculated by the least square method. Note that depending on the curvature of $V_{\text{OUT}}(I_P)$, E_{LIN} can be positive or negative.

Total Output Error (E_{TOT})

 E_{TOT} (in %) is the relative difference between the sensor output and the ideal output at a given primary current (I_P). E_{TOT} can be estimated with Equation (2):

$$\mathsf{E}_{\mathsf{TOT}}(\mathsf{I}_{\mathsf{P}}) = \frac{\mathsf{V}_{\mathsf{OUT}}(\mathsf{I}_{\mathsf{P}}) - \mathsf{V}_{\mathsf{OUT_IDEAL}}(\mathsf{I}_{\mathsf{P}})}{\mathsf{SENS} \times \mathsf{I}_{\mathsf{P}}} \times 100 \quad (2)$$



Where V_{OUT_IDEAL} can be calculated with Equation (3):

$$V_{OUT_IDEAL}(I_{P}) = \frac{VCC}{2} + SENS \times I_{P}$$

The total output error incorporates all error sources, and is a function of I_P. At currents close to I_{PMAX}, E_{TOT} is affected mainly by the sensitivity error. At currents close to 0A, E_{TOT} is mostly caused by the offset voltage (V_{OE}). Note that when I_P = 0A, E_{TOT} diverges to infinity due to the constant offset.

Ratiometry Coefficients

Generally, the sensor output is ratiometric. This means that the sensitivity and the zero current output scale with VDD. The ratiometry coefficients measure if the sensitivity and zero output current are proportional.

K_{SENS} can be estimated with Equation (4):

 $K_{SENS} = \frac{SENS(VCC) / SENS(5V)}{VCC / 5V}$

(4)

(3)

 K_{VO} can be calculated with Equation (5):

$$K_{VO} = \frac{V_{OUT}(I_{P} = 0 \text{ to } VCC) / V_{OUT}(I_{P} = 0 \text{ to } 5V)}{VCC/5V}$$
(5)

It is recommended for K_{SENS} and K_{VO} to be equal to 1.

Power On Time (t_{PO})

The power on time (t_{PO}) is the time interval after power is first applied to the device, until the output can correctly indicate the applied primary current. t_{PO} is defined as the time between the following moments:

- <u>t1</u>: The supply reaches the minimum operating voltage (VCC_{MIN}).
- <u>t2</u>: V_{OUT} settles within ±10% of its steady state value under an applied primary current (see Figure 5).

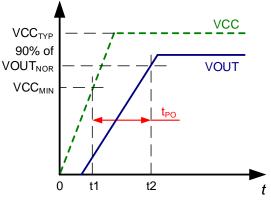


Figure 5: Power-On Time (tPO)

Propagation Delay (tpd)

The propagation delay (t_{PD}) represents the internal latency between an event that has been measured and the sensor's response. t_{PD} is defined as the time between the following moments:

- 1. <u>t1</u>: The primary current signal reaches 20% of I_{P_MAX} .
- 2. <u>t2</u>: V_{OUT} reaches 20% of VOUT_{MAX} (see Figure 6).

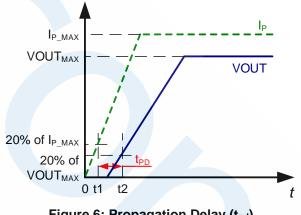


Figure 6: Propagation Delay (tpd)

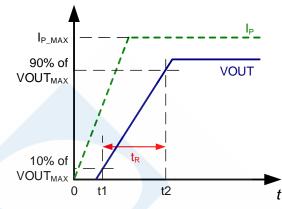
Rising Time (t_R)

The rising time (t_R) is defined as the time between the following moments:

1. <u>t1</u>: The sensor's V_{OUT} reaches 10% of its full scale value.

<u>t2</u>: The sensor's V_{OUT} reaches 90% of its full scale value (see Figure 7).







The sensor bandwidth (f_{BW}) is defined as the 3dB cutoff frequency.

By using the rising time, f_{BW} can be estimated with Equation (6):

$$f_{BW} = 0.35 / t_{R}$$
 (6)

Response Time (tresponse)

The response time (t_{RESPONSE}) is defined as the time between the following moments:

- 1. <u>t1</u>: The primary current signal reaches 90% of its final value.
- <u>t2</u>: V_{OUT} reaches 90% of its output, as it corresponds to the applied primary current (see Figure 8).

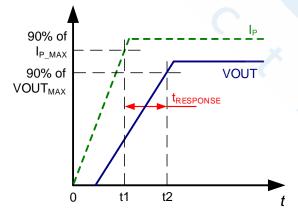


Figure 8: Response Time (tresponse)

Remove the ground and power planes under the IC to reduce the effect of eddy currents on t_R and $t_{RESPONSE}$.

Adjustable Bandwidth

The sensor dynamic can be adjusted with an external capacitor (C_F). In this scenario, the bandwidth (f_{BW}) can be calculated with Equation (7):

$$f_{BW} = \frac{1}{2\pi} \times \frac{1}{R_{Fi}(C_{Fi} + C_F)}$$
 (7)

Figure 9 shows the typical bandwidth curve.

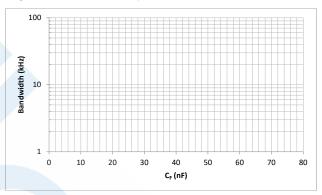


Figure 9: Bandwidth vs. CF



APPLICATION INFORMATION

Self-Heating Performance

The conductor and MCS1801 temperatures can rise when current flows through the primary conductor. This means that self-heating should be carefully verified to ensure that the IC junction temperature does not exceed the maximum value (see the Absolute Maximum Ratings on page 3).

The thermal behavior strongly depends on the thermal environment of the IC, as well as its cooling capacity. In particular, thermal behavior depends on the PCB copper area's thickness. The thermal response is also related to the current waveform's profile (e.g. the amplitude and frequency of an AC current, or the peaks and duty cycle of a pulsed DC current).

Figure 10 shows the self-heating performance of the MCS1801 with a DC current input. The data is collected when the MCS1801 is mounted on the device's evaluation board and $T_A = 25^{\circ}$ C. Values were taken 10 minutes after a continuous current.

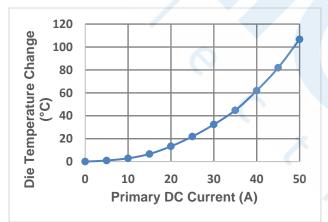
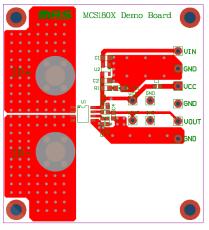
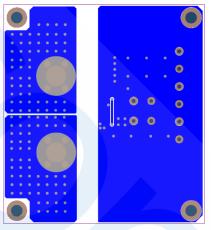


Figure 10: Self-Heating Performance with DC Current Input

Figure 11 shows the top and bottom layers of the PCB. The board includes a total of 2200mm², 4oz (139µm) copper connected to the primary conductor by the IP+ and IP- pins. The copper covers both the top and bottom sides, and thermal vias connect the two layers.



Top Layer



Bottom Layer Figure 11: Recommended PCB Layout



TYPICAL APPLICATION CIRCUIT

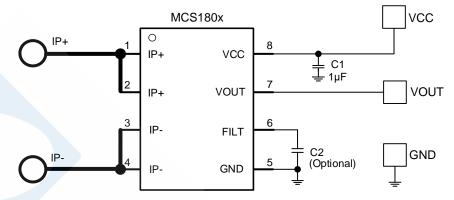
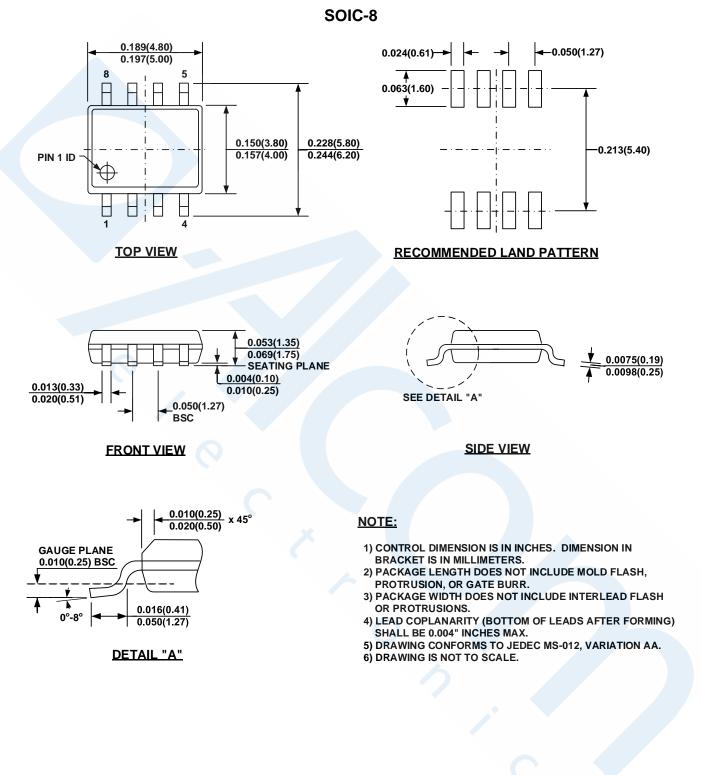


Figure 12: Typical Application Circuit

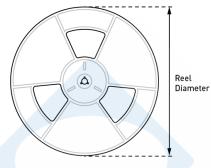


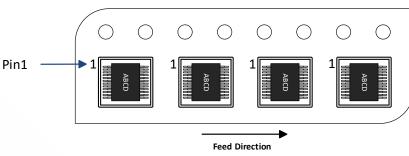
PACKAGE INFORMATION





CARRIER INFORMATION





Part Number	Package Description	Quantity/ Reel	Quantity/ Tube	Quantity/ Tray	Reel Diameter	Carrier Tape Width	Carrier Tape Pitch
MCS1801GS-12-Z	SOIC-8	2500	N/A	N/A	13in	12mm	8mm
MCS1801GS-25-Z	SOIC-8	2500	N/A	N/A	13in	12mm	8mm



REVISION HISTORY

Revision #	Revision Date	Description	Pages Updated
1.0	4/13/2021	Initial Release	-



Singel 3 | B-2550 Kontich | Belgium | Tel. +32 (0)3 458 30 33 info@alcom.be | www.alcom.be Rivium 1e straat 52 | 2909 LE Capelle aan den IJssel | The Netherlands Tel. +31 (0)10 288 25 00 | info@alcom.nl | www.alcom.nl

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